

HV9803

LED Driver IC with Average-Mode Constant Current Control

Features

- Fast Average Current Control
- Correction for Propagation Delay and Offset
 Voltage
- · Fixed Offtime Switching Mode
- Linear Dimming Input
- PWM Dimming Input
- Output Short-Circuit Protection with Programmable Skip Mode
- Input Undervoltage Shutdown

Applications

- Backlighting of LCD Panels
- · General Lighting

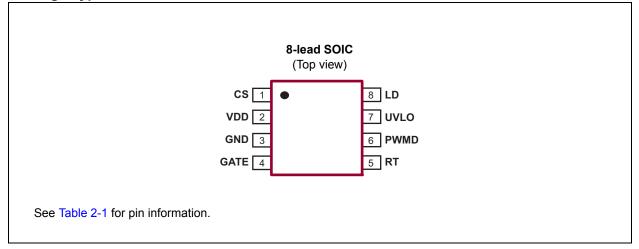
General Description

The HV9803 is an open-loop, Average-mode current control LED driver IC operating in a constant Offtime mode. The IC features $\pm 2\%$ current accuracy and tight line and load regulation of the LED current without any need for loop compensation or high-side current sensing. Its auto-zero circuit cancels the effect of both the input offset voltage and the propagation delay in the current sense comparator.

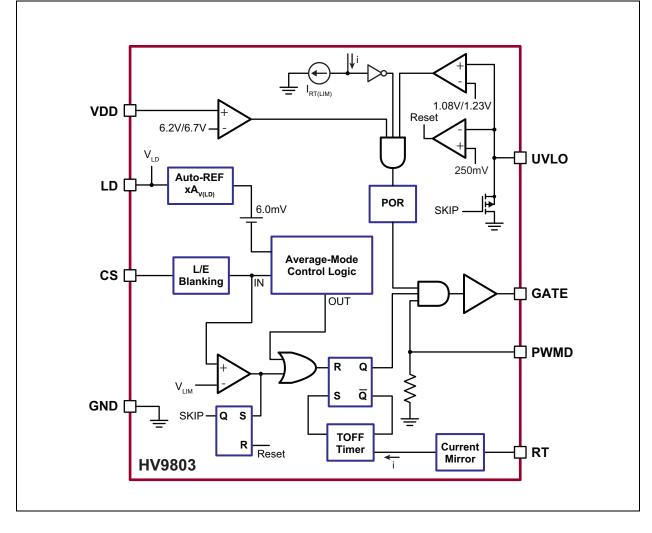
The HV9803 can be powered from a 7V to 13.2V supply. The IC features fast PWM dimming response. The linear dimming input LD can accept a reference voltage of up to 2.5V.

The IC is equipped with a current limit comparator for Hiccup-mode output short-circuit protection. It also features a programmable input undervoltage shutdown.

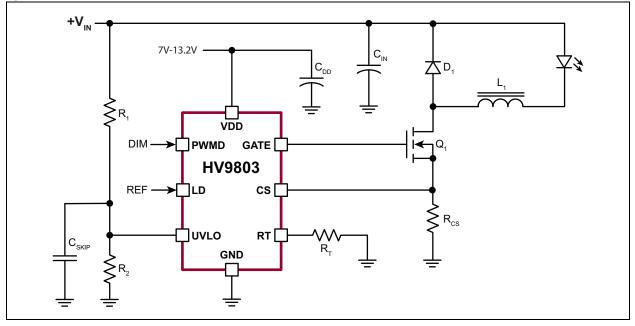
Package Type



Functional Block Diagram



Typical Application Circuit



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings†

V _{DD} , GATE, CS	
LD, RT, PWMD, UVLO	
Junction Temperature, T _J	
Storage Temperature, T _S	
Power Dissipation (at 25 °C):	
8-lead SOIC	

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

SHORT-CIRCUIT PROTECTIONduty cycle.Current Limit Threshold Voltage V_{LIM} 1.571.751.93VCurrent Limit Delay CS-to-GATE T_{DELAY} 150ns $V_{CS} = V_{LIM} + 30 \text{ mV}$ UVLO Skip Timer Reset SwitchBurnar500O	Parameter	Sym.	Min.	Тур.	Max	Unit	Conditions
DubberDubb	INPUT						
V_{DD} UNDERVOLTAGE LOCKOUT $V_{DDUV,R}$ 6.456.76.95 V V_{DD} Rising V_{DD} Undervoltage Lockout Upper Threshold ΔV_{DDUV} -500-mV V_{DD} Rising V_{DD} Undervoltage Lockout Hysteresis ΔV_{DDUV} -500-mV V_{DD} Falling PWM DIMMING PWMD Input Low Voltage $V_{PWMD(LO)}$ 1VPWMD Input High Voltage $V_{PWMD(HI)$ 2.6VInternal Pull-Down Resistance at PWMD R_{PWMD} 50100150k Ω CURRENT SENSE COMPARATORExternal Reference Voltage V_{LD} 0-3VCS Threshold Voltage V_{CST} 762778794 955 mV $V_{LD} = 1.6V$ Current Sense Blanking Interval T_{BLANK} 150-280nsImage: Second constraint on output LED current may occur beyon duty cycle.Maximum Steady State Duty Cycle D_{MAX} 80 M_{SC} Reduction in output LED current may occur beyon duty cycle.SHORT-CIRCUIT PROTECTION V_{LIM} 1.571.751.93V $V_{CS} = V_{LIM} + 30$ mVUVLO Skip Timer Reset Switch $R_{PUDOR150\OmegaQ_{CS} = V_{LIM} + 30 mV$	Input DC Supply Voltage Range	V _{DD}	_		13.2	V	DC input voltage
VDD DUDUC ThresholdVDDUV,R DUDUK Model6.456.76.95VVDD VDD RisingVDD Undervoltage Lockout Hysteresis ΔV_{DDUV} -500-mVVDD RisingPWM DIMMINGPWMD Input Low Voltage $V_{PWMD(LO)}$ 1VPWMD Input High Voltage $V_{PWMD(HII)}$ 2.6VInternal Pull-Down Resistance at PWMD R_{PWMD} 50100150k Ω CURRENT SENSE COMPARATORExternal Reference Voltage V_{LD} 0-3VCS Threshold Voltage V_{LD} 0-3VCS Threshold Voltage V_{LD} 0Current Sense Blanking IntervalTBLANK150-280nsMinimum On-TimeTON(MIN)760nsVCS = 0.5 VLD + 30 mVMaximum Steady State Duty Cycle D_{MAX} 80%Reduction in output LED current may occur beyon duty cycle.SHORT-CIRCUIT PROTECTIONVLIM1.571.751.93VVCS = VLIM + 30 mVUVLO Skip Timer Reset Switch P_{LUM} 150nsVCS = VLIM + 30 mV	Quiescent V _{DD} Supply Current	I _{DD}	_	1.5	2.5	mA	V _{CS} = 0V
Threshold $V_{DDUV,R}$ 6.436.76.93V V_{DD} Rising V_{DD} Undervoltage Lockout Hysteresis ΔV_{DDUV} —500—mV V_{DD} FallingPWM DIMMINGPWMD Input Low Voltage $V_{PWMD(LO)}$ ——1VPWMD Input High Voltage $V_{PWMD(HI)}$ 2.6——VInternal Pull-Down Resistance at PWMD R_{PWMD} 50100150k Ω CURRENT SENSE COMPARATORExternal Reference Voltage V_{LD} 0—3VCS Threshold Voltage V_{CST} 762778794 955mV V_{LD} = 1.6VCS Threshold Voltage $\Lambda_{V(LD)}$ —0.49———Current Sense Blanking Interval T_{BLANK} 150—280nsIsMinimum On-Time $T_{ON(MIN)}$ ——760ns V_{CS} = 0.5 V_{LD} + 30 mVMaximum Steady State Duty Cycle D_{MAX} 80—— M_{CS} Reduction in output LED current may occur beyon duty cycle.SHORT-CIRCUIT PROTECTION T_{DELAY} ——150ns V_{CS} = V_{LIM} + 30 mVUVLO Skip Timer Reset Switch R_{UDDZ} ——500Q Q_{DS}	V _{DD} UNDERVOLTAGE LOCKOUT						
PWM DIMMINGPWMD Input Low Voltage $V_{PWMD(LO)}$ $ 1$ V PWMD Input High Voltage $V_{PWMD(HI)}$ 2.6 $ V$ Internal Pull-Down Resistance at PWMD $S00$ 100 150 $k\Omega$ CURRENT SENSE COMPARATORExternal Reference Voltage V_{LD} 0 $ 3$ V CS Threshold Voltage V_{LD} 0 $ 3$ V CS Threshold Voltage V_{LD} 0 $ 3$ V Lot CS Voltage Ratio $A_{V(LD)}$ $ 0.49$ $ -$ Current Sense Blanking Interval T_{BLANK} 150 $ 280$ nsMinimum On-Time $T_{ON(MIN)$ $ 760$ ns $V_{CS} = 0.5 V_{LD} + 30 \text{ mV}$ Maximum Steady State Duty Cycle D_{MAX} 80 $ \%$ Reduction in output LED current may occur beyon duty cycle.SHORT-CIRCUIT PROTECTIONCurrent Limit Threshold Voltage V_{LIM} 1.57 1.75 1.93 V Current Limit Delay CS-to-GATE T_{DELAY} $ 150$ ns $V_{CS} = V_{LIM} + 30 \text{ mV}$ UVLO Skip Timer Reset Switch B_{WROZ} $ 500$ O 0		V _{DDUV,R}	6.45	6.7	6.95	V	V _{DD} Rising
PWMD Input Low Voltage $V_{PWMD(LO)}$ 1VPWMD Input High Voltage $V_{PWMD(HI)}$ 2.6VInternal Pull-Down Resistance at PWMD R_{PWMD} 50100150kΩCURRENT SENSE COMPARATORExternal Reference Voltage V_{LD} 03VCS Threshold Voltage V_{CST} 762778794 955 mV V_{LD} = 1.6VCorrent Sense Blanking IntervalT _{BLANK} 150280nsMinimum On-Time $T_{ON(MIN)}$ 760ns V_{CS} = 0.5 V_{LD} + 30 mVMaximum Steady State Duty Cycle D_{MAX} 80%Reduction in output LED current may occur beyon duty cycle.SHORT-CIRCUIT PROTECTIONCurrent Limit Threshold Voltage V_{LIM} 1.571.751.93VUVLO Skip Timer Reset Switch R_{WROZ} 500Q0	V _{DD} Undervoltage Lockout Hysteresis	ΔV_{DDUV}	_	500		mV	V _{DD} Falling
PWMD Input High VoltageV PWMD(Hi)V 2.6VInternal Pull-Down Resistance at PWMDR PWMDR PWMD50100150kΩCURRENT SENSE COMPARATORExternal Reference VoltageV V D0-3VCS Threshold VoltageV VCST762778794 955mVV V DV DLD to CS Voltage RatioA V(LD)-0.49Current Sense Blanking IntervalT T DN(MIN)150-280ns-Minimum On-TimeT ON(MIN)760nsV CS = 0.5 VLD + 30 mVMaximum Steady State Duty CycleD MAX80%Reduction in output LED current may occur beyon duty cycle.SHORT-CIRCUIT PROTECTIONV LIM1.571.751.93VV CS = VLIM + 30 mVUVLO Skip Timer Reset SwitchR R R R R R N500Q0	PWM DIMMING			•	•	•	
Internal Pull-Down Resistance at PWMDR PWMDR F PWMD50100150kΩCURRENT SENSE COMPARATORExternal Reference Voltage V_{LD} 03VCS Threshold Voltage V_{CST} 762778794 955mV V_{LD} = 1.6VCS Threshold Voltage $A_{V(LD)}$ 0.49Current Sense Blanking Interval T_{BLANK} 150280nsMinimum On-Time $T_{ON(MIN)}$ 760ns V_{CS} = 0.5 V_{LD} + 30 mVMaximum Steady State Duty Cycle D_{MAX} 80%Reduction in output LED current may occur beyon duty cycle.SHORT-CIRCUIT PROTECTION V_{LIM} 1.571.751.93VVCurrent Limit Threshold Voltage V_{LIM} 1.571.751.93VVUVLO Skip Timer Reset Switch R_{WURDZ} 500Q	PWMD Input Low Voltage	V _{PWMD(LO)}	—		1	V	
PWMDRPWMD50100150KΩCURRENT SENSE COMPARATORExternal Reference Voltage V_{LD} 03VCS Threshold Voltage V_{CST} 762778794 mV V_{LD} = 1.6VLD to CS Voltage Ratio $A_{V(LD)}$ 0.49Current Sense Blanking Interval T_{BLANK} 150280nsMinimum On-Time $T_{ON(MIN)}$ 760ns V_{CS} = 0.5 V_{LD} + 30 mVMaximum Steady State Duty Cycle D_{MAX} 80%Reduction in output LED current may occur beyon duty cycle.SHORT-CIRCUIT PROTECTION V_{LIM} 1.571.751.93VVCurrent Limit Threshold Voltage V_{LIM} 1.571.751.93VVUVLO Skip Timer Reset Switch B_{WDDDZ} 500OO	PWMD Input High Voltage	V _{PWMD(HI)}	2.6	—		V	
External Reference Voltage V_{LD} 03VCS Threshold Voltage V_{CST} 762 778 794 mV $V_{LD} = 1.6V$ LD to CS Voltage Ratio $A_{V(LD)}$ 0.49 Current Sense Blanking Interval T_{BLANK} 150 280 nsMinimum On-Time $T_{ON(MIN)}$ 760 ns $V_{CS} = 0.5 V_{LD} + 30 \text{ mV}$ Maximum Steady State Duty Cycle D_{MAX} 80 $\%$ Reduction in output LED current may occur beyon duty cycle.SHORT-CIRCUIT PROTECTION V_{LIM} 1.57 1.75 1.93 V $V_{CS} = V_{LIM} + 30 \text{ mV}$ UVLO Skip Timer Reset Switch P_{LIMPAR} $$ $$ 500 0 0		R _{PWMD}	50	100	150	kΩ	
CS Threshold Voltage V_{CST} 762 778 794 955 mV $V_{LD} = 1.6V$ $V_{LD} = 2V$ LD to CS Voltage Ratio $A_{V(LD)}$ $ 0.49$ $ -$ Current Sense Blanking Interval T_{BLANK} 150 $ 280$ nsMinimum On-Time $T_{ON(MIN)}$ $ 760$ ns $V_{CS} = 0.5 V_{LD} + 30 \text{ mV}$ Maximum Steady State Duty Cycle D_{MAX} 80 $ \%$ SHORT-CIRCUIT PROTECTION V_{LIM} 1.57 1.75 1.93 V Current Limit Delay CS-to-GATE T_{DELAY} $ 150$ ns $V_{CS} = V_{LIM} + 30 \text{ mV}$ UVLO Skip Timer Reset Switch B_{WR02T} $ 500$ 0 0	CURRENT SENSE COMPARATOR			•	•	•	•
CS Inreshold Voltage V_{CST} 955975995 mV $V_{LD} = 2V$ LD to CS Voltage Ratio $A_{V(LD)}$ - 0.49 Current Sense Blanking Interval T_{BLANK} 150-280nsMinimum On-Time $T_{ON(MIN)}$ 760ns $V_{CS} = 0.5 V_{LD} + 30 \text{ mV}$ Maximum Steady State Duty Cycle D_{MAX} 80%Reduction in output LED current may occur beyon duty cycle.SHORT-CIRCUIT PROTECTIONCurrent Limit Threshold Voltage V_{LIM} 1.571.751.93VCurrent Limit Delay CS-to-GATE T_{DELAY} 150ns $V_{CS} = V_{LIM} + 30 \text{ mV}$ UVLO Skip Timer Reset SwitchBuygaz50000	External Reference Voltage	V _{LD}	0	_	3	V	
UnderstandUser955975995 $V_{LD} = 2V$ LD to CS Voltage Ratio $A_{V(LD)}$ -0.49Current Sense Blanking Interval T_{BLANK} 150-280nsMinimum On-Time $T_{ON(MIN)}$ 760ns $V_{CS} = 0.5 V_{LD} + 30 \text{ mV}$ Maximum Steady State Duty Cycle D_{MAX} 80%Reduction in output LED current may occur beyon duty cycle.SHORT-CIRCUIT PROTECTIONCurrent Limit Threshold Voltage V_{LIM} 1.571.751.93VCurrent Limit Delay CS-to-GATE T_{DELAY} 150ns $V_{CS} = V_{LIM} + 30 \text{ mV}$ UVLO Skip Timer Reset SwitchBurgan50000	CS Threshold Voltage	V	762	778	794	m\/	V _{LD} = 1.6V
Current Sense Blanking Interval T_{BLANK} 150 $-$ 280nsMinimum On-Time $T_{ON(MIN)}$ $ -$ 760ns $V_{CS} = 0.5 V_{LD} + 30 \text{ mV}$ Maximum Steady State Duty Cycle D_{MAX} 80 $ \%$ Reduction in output LED current may occur beyon duty cycle.SHORT-CIRCUIT PROTECTIONCurrent Limit Threshold Voltage V_{LIM} 1.571.751.93VCurrent Limit Delay CS-to-GATE T_{DELAY} $ -$ 150ns $V_{CS} = V_{LIM} + 30 \text{ mV}$ UVLO Skip Timer Reset Switch B_{UVRDZ} $ -$ 500 O O		V CST	955	975	995	IIIV	$V_{LD} = 2V$
Minimum On-Time $T_{ON(MIN)}$ 760ns $V_{CS} = 0.5 V_{LD} + 30 \text{ mV}$ Maximum Steady State Duty Cycle D_{MAX} 80 $\%$ Reduction in output LED current may occur beyon duty cycle.SHORT-CIRCUIT PROTECTIONCurrent Limit Threshold Voltage V_{LIM} 1.571.751.93VCurrent Limit Delay CS-to-GATE T_{DELAY} 150ns $V_{CS} = V_{LIM} + 30 \text{ mV}$ UVLO Skip Timer Reset Switch	LD to CS Voltage Ratio	A _{V(LD)}	_	0.49	_	_	
Maximum Steady State Duty Cycle D _{MAX} 80 — — % Reduction in output LED current may occur beyon duty cycle. SHORT-CIRCUIT PROTECTION Current Limit Threshold Voltage V _{LIM} 1.57 1.75 1.93 V Current Limit Delay CS-to-GATE T _{DELAY} — — 150 ns V _{CS} = V _{LIM} + 30 mV UVLO Skip Timer Reset Switch Burnez — — 500 O	Current Sense Blanking Interval	T _{BLANK}	150	_	280	ns	
Maximum Steady State Duty Cycle D_{MAX} 80%current may occur beyon duty cycle.SHORT-CIRCUIT PROTECTIONCurrent Limit Threshold Voltage V_{LIM} 1.571.751.93VCurrent Limit Delay CS-to-GATE T_{DELAY} 150ns $V_{CS} = V_{LIM} + 30 \text{ mV}$ UVLO Skip Timer Reset SwitchBurgan5000	Minimum On-Time	T _{ON(MIN)}	_	_	760	ns	V_{CS} = 0.5 V_{LD} + 30 mV
Current Limit Threshold Voltage V_{LIM} 1.571.751.93VCurrent Limit Delay CS-to-GATE T_{DELAY} 150ns $V_{CS} = V_{LIM} + 30 \text{ mV}$ UVLO Skip Timer Reset SwitchBuygar5000	Maximum Steady State Duty Cycle	D _{MAX}	80	_	_	%	current may occur beyond this
Current Limit Delay CS-to-GATE T_{DELAY} —150ns $V_{CS} = V_{LIM} + 30 \text{ mV}$ UVLO Skip Timer Reset SwitchBuygar—5000	SHORT-CIRCUIT PROTECTION						
UVLO Skip Timer Reset Switch	Current Limit Threshold Voltage	V _{LIM}	1.57	1.75	1.93	V	
B_{10} (part A_{10} A_{1	Current Limit Delay CS-to-GATE	T _{DELAY}	_	—	150	ns	$V_{CS} = V_{LIM} + 30 \text{ mV}$
Resistance	UVLO Skip Timer Reset Switch Resistance	R _{UVRST}		_	500	Ω	

DC ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Specifications : Specifications apply over the full operating ambient temperature range, $T_A = -40^{\circ}$ C to +125°C. Unless otherwise noted, $T_A = 25^{\circ}$ C, $V_{DD} = 12$ V and $V_{PWMD} = 5$ V.								
Parameter	Sym.	Min.	Тур.	Мах	Unit	Conditions		
UVLO Skip Timer Reset Voltage	V _{UVRST}	200	-	300	mV			
Minimum On-Time (Short Circuit)	T _{ON(MIN)}	_		430	ns	V _{CS} = V _{LIM} + 30 mV		
T _{OFF} TIMER								
Offtime	т	6.7	9	11.3	μs	R _T = 250 kΩ		
Ontime	T _{OFF}	0.8	1	1.2	μs	R _T = 25 kΩ		
RT Overcurrent Threshold	I _{RT(LIM)}	—	2.8		mA			
GATE DRIVER		•		•	•			
Gate Sourcing Current	ISOURCE	0.165			Α	V _{GATE} = 0V		
Gate Sinking Current	I _{SINK}	0.165	_		Α	V _{GATE} = V _{DD}		
GATE Output Rise Time	t _{RISE}	—	30	50	ns	C _{GATE} = 500 pF		
GATE Output Fall Time	t _{FALL}	—	30	50	ns	C _{GATE} = 500 pF		
UVLO								
Undervoltage Upper Threshold Voltage	V _{UVLO,R}	1.17	1.23	1.29	V	V _{UVLO} rising		
Undervoltage Threshold Voltage Hysteresis	ΔV _{UVLO}	_	150	_	mV	V _{UVLO} falling		

TEMPERATURE SPECIFICATIONS

Parameter	Sym.	Min.	Тур.	Max.	Unit	Conditions
TEMPERATURE RANGE						
Operating Ambient Temperature	Τ _Α	-40	—	+125	°C	
Maximum Junction Temperature	ТJ	—	—	+150	°C	
Storage Temperature	Τ _S	-65	—	+150	°C	
PACKAGE THERMAL RESISTANCE						
8-lead SOIC	θ_{JA}		101		°C/W	

2.0 PIN DESCRIPTION

The details on the pins of HV9803 are listed in Table 2-1. See location of pins in **Package Type**.

Pin Number	Pin Name	Description
1	CS	This pin is the current sense pin used to detect the MOSFET source current by means of an external sense resistor.
2	VDD	This is the power supply input for the GATE output and input of the low-voltage regulator powering the internal logic. It must be bypassed with a low-ESR capacitor to GND (at least 0.1 μ F).
3	GND	Ground return for all internal circuitry. This pin must be electrically connected to the ground of the power train.
4	GATE	This pin is the output of gate driver for an external N-channel power MOSFET.
5	RT	A resistor connected between RT and GND programs the GATE offtime.
6	PWMD	This is the PWM dimming input of the IC. When this pin is pulled to GND, the gate driver is turned off. When the pin is pulled high, the gate driver operates normally.
7	UVLO	This pin is the undervoltage comparator input. It is also used to program a short-circuit protection skip delay.
8	LD	This pin is the reference voltage input for programming the LED current.

TABLE 2-1: PIN FUNCTION TABLE

3.0 FUNCTIONAL DESCRIPTION

3.1 General

The peak-current control of a buck converter is the most economical and simplest way to regulate its output current. However, it suffers accuracy and regulation problems that arise from the peak-to-average current error due to the current ripple in the output inductor and the propagation delay in the current sense comparator. The full inductor current signal is unavailable for switch current sensing with current-sensing resistor in the ground path between the low-side switch and ground in a buck converter with low-side main switch configuration when the switch is turned-on. While it is very simple to detect the peak current in the switch, controlling the average inductor current is usually implemented by level-translating the current sense signal from the positive input supply rail. While this is practical for relatively low-input voltage, this type of average-current control may become excessively complex and expensive in the case of input voltages above 100V.

The HV9803 uses a control scheme that senses only the switch current to quickly and accurately control the average current in the buck inductor. No compensation of the current control loop is required. The inductor current ripple amplitude does not affect this control scheme significantly. The LED current is independent of the variation in inductance, switching frequency and output voltage. Constant offtime control of the buck converter is used for stability and to improve the LED current regulation over a wide range of input voltages. The IC features excellent PWM dimming response.

3.2 OFF Timer

In the HV9803, the timing resistor connected at the RT pin determines the offtime of the gate driver, and the resistor must be wired to GND. The equation governing the offtime of the GATE output is derived with Equation 3-1.

EQUATION 3-1:

 $T_{OFF} = R_T \times 40 pF$

The RT input is protected from short circuit. Overcurrent condition at RT inhibits the IC.

3.3 Current Sense Comparator and Timer Circuits

The function of the HV9803's current sense comparator is similar to that of a peak current controller. However, the GATE pulse is not terminated immediately as the CS threshold is met. The GATE turn-off in the nth cycle is delayed by a time $T_{2,n}$ determined by a timer circuit as shown in Equation 3-2.

EQUATION 3-2:

 $T_{2,n} = \frac{1}{2} \times (T_{1,n} + T_{1,n-1})$

Where $T_{1,n}$ and $T_{1,n-1}$ are the times to the CS threshold in any two consecutive switching cycles.

This iterative control law is needed for damping sub-harmonic oscillation. Note that the control law is only valid up to a maximum switching duty cycle, $D_{MAX} = 0.8$. Exceeding D_{MAX} will cause a reduction in the LED current.

Propagation delay in the current sense comparator is one of the most significant contributors to the LED current error. It must be noted that the control scheme described above does not improve this deficiency of the peak-current control scheme by itself. Moreover, it samples the propagation delay during T_1 and replicates it during T_2 , essentially doubling the error introduced by this delay. To eliminate this error, the reference voltage is corrected by an auto-zero circuit. In essence, the HV9803 samples its CS signal when the current sense comparator triggers and detects the difference between the sampled CS level and the reference input of the current sense comparator. The resulting difference is subtracted from the reference level to generate a new reference in the next switching cycle.

3.4 GATE Output

The GATE output of the HV9803 is used to drive an external MOSFET. It is recommended that the gate charge Q_G of the external MOSFET should be less than 25 nC for switching frequencies ≤ 100 kHz and less than 15 nC for switching frequencies > 100 kHz.

The resulting LED current is calculated using Equation 3-3.

EQUATION 3-3:

$$I_{LED} = \frac{0.49 \times V_{LD} - 6mV}{R_{CS}}$$

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3.5 Short-Circuit Protection

The HV9803 is equipped with a short-circuit protection comparator having another CS threshold V_{LIM}. When this second threshold is triggered, the GATE output shuts off for the duration of a restart delay, determined by the RC constant set at UVLO pin. Meanwhile, the capacitor C_{SKIP} is discharged below 200 mV. The restart delay due to charging C_{SKIP} to the UVLO upper threshold is calculated as shown in Equation 3-4.

EQUATION 3-4:

 $T_{SKIP} = k \times R_1 \times \overline{C_{SKIP}} \times In \times \left(\frac{k \times V_{IN} - 0.30V}{k \times V_{IN} - 1.17V}\right)$ Where: $k = \frac{R_2}{R_1 + R_2}$

3.6 Undervoltage Shutdown

Undervoltage comparator input is provided to disable the IC when the UVLO input is below the UVLO lower threshold. Hysteresis is provided to avoid oscillation.

3.7 Failure Modes and Effects Analysis (FMEA)

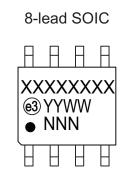
The HV9803 is designed to withstand short circuit between its adjacent pins without damage. Table 3-1 describes the effect of such incidental short-circuit conditions.

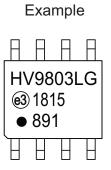
TABLE 3-1: SHORT-CIRCUIT MODES AND EFFECTS	
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Short-Circuit Mode	Effect
CS to V _{DD}	The IC triggers the short-circuit protection and operates in the Auto-restart mode continu- ously.
V _{DD} to GND	Short circuit across the 12V should cause the external bias supply overcurrent protection.
GND to GATE	This should cause the external bias supply overcurrent protection. The power MOSFET Q1 is off.
RT to PWMD	 Case 1–PWMD = Lo: The RT pin sources its maximum current. GATE = 0V and Q1 is off. Case 2–PWMD = Hi: The RT pin is pulled up, shutting off the timer. GATE is off.
PWMD to UVLO	This overdrives the undervoltage threshold. However, since the $V_{\rm IN}UV$ condition is harmless to the IC, there is no effect.
UVLO to LD	LD overdrives the UVLO. If LD is lower than the UVLO lower threshold, the IC shuts off. No effect otherwise.

4.0 PACKAGING INFORMATION

4.1 Package Marking Information

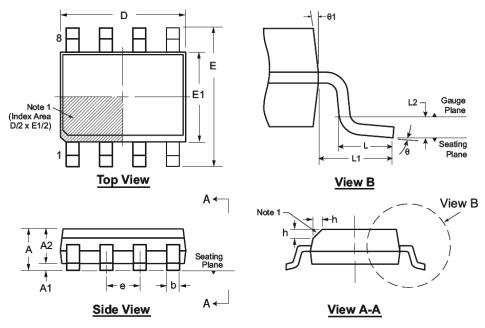




Legend	: XXX Y YY WW NNN @3 *	Product Code or Customer-specific information Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code Pb-free JEDEC [®] designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.
Note:	be carrie characters	nt the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available s for product code or customer-specific information. Package may or e the corporate logo.

8-Lead SOIC (Narrow Body) Package Outline (LG/TG)

4.90x3.90mm body, 1.75mm height (max), 1.27mm pitch



Note: For the most current package drawings, see the Microchip Packaging Specification at www.microchip.com/packaging.

Note:

1. This chamfer feature is optional. A Pin 1 identifier must be located in the index area indicated. The Pin 1 identifier can be: a molded mark/identifier; an embedded metal marker; or a printed indicator.

Symbo	1	A	A1	A2	b	D	E	E1	e	h	L	L1	L2	θ	θ1
	MIN	1.35*	0.10	1.25	0.31	4.80*	5.80*	3.80*		0.25	0.40			0 0	5 ⁰
Dimension (mm)	NOM	-	-	-	-	4.90	6.00	3.90	1.27 BSC	-	-	1.04 REF	0.25 BSC	-	-
()	MAX	1.75	0.25	1.65*	0.51	5.00*	6.20*	4.00*		0.50	1.27			8 0	15 ⁰

JEDEC Registration MS-012, Variation AA, Issue E, Sept. 2005.

* This dimension is not specified in the JEDEC drawing.

Drawings are not to scale.

APPENDIX A: REVISION HISTORY

Revision A (August 2018)

- Converted Supertex Doc# DSFP-HV9803 to Microchip DS20005641A
- Changed the packaging quantity for the 8-lead SOIC LG package from 2500/Reel to 3300/Reel
- Added a maximum junction temperature to the Temperature Specifications Table
- Made minor text changes throughout the document

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

PART NO.	<u>xx</u>	- <u>x</u> - x	Example:
Device	Package Options	Environmental Media Type	a) HV9803LG-G: LED Driver IC with Average-Mode Constant Current Control, 8-lead SOIC Package, 3300/Reel
Device:	HV9803 =	LED Driver IC with Average-Mode Constant Current Control	
Package:	LG =	8-lead SOIC	
Environmental:	G =	Lead (Pb)-free/RoHS-compliant Package	
Media Type:	(blank) =	3300/Reel for an LG Package	
L			

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